

ESP32-S3-WROOM-1

ESP32-S3-WROOM-1U

Datasheet

2.4 GHz Wi-Fi (802.11 b/g/n) and Bluetooth® 5 (LE) module

Built around ESP32-S3 series of SoCs, Xtensa® dual-core 32-bit LX7 microprocessor

Flash up to 16 MB, PSRAM up to 8 MB

36 GPIOs, rich set of peripherals

On-board PCB antenna



ESP32-S3-WROOM-1



ESP32-S3-WROOM-1U



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Espressif Systems
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1 Module Overview

Note:

Check the link or the QR code to make sure that you use the latest version of this document:

https://www.espressif.com/documentation/esp32-s3-wroom-1_wroom-1u_datasheet_en.pdf



1.1 Features

CPU and On-Chip Memory

- ESP32-S3 series of SoCs embedded, Xtensa® dual-core 32-bit LX7 microprocessor, up to 240 MHz
- 384 KB ROM
- 512 KB SRAM
- 16 KB SRAM in RTC
- Up to 8 MB PSRAM

Wi-Fi

- 802.11 b/g/n
- Bit rate: 802.11n up to 150 Mbps
- A-MPDU and A-MSDU aggregation
- 0.4 μ s guard interval support
- Center frequency range of operating channel: 2412 ~ 2484 MHz

Bluetooth

- Bluetooth LE: Bluetooth 5, Bluetooth mesh
- Speed: 125 Kbps, 500 Kbps, 1 Mbps, 2 Mbps
- Advertising extensions
- Multiple advertisement sets
- Channel selection algorithm #2
- Internal co-existence mechanism between Wi-Fi and Bluetooth to share the same antenna

Peripherals

- GPIO, SPI, LCD interface, Camera interface, UART, I2C, I2S, remote control, pulse counter,

LED PWM, USB 1.1 OTG, USB Serial/JTAG controller, MCPWM, SDIO host, GDMA, TWAI® controller (compatible with ISO 11898-1), ADC, touch sensor, temperature sensor, timers and watchdogs

Note:

* Please refer to [ESP32-S3 Series Datasheet](#) for detailed information about the module peripherals.

Integrated Components on Module

- 40 MHz crystal oscillator
- Up to 16 MB Quad SPI flash

Antenna Options

- On-board PCB antenna (ESP32-S3-WROOM-1)
- External antenna via a connector (ESP32-S3-WROOM-1U)

Operating Conditions

- Operating voltage/Power supply: 3.0 ~ 3.6 V
- Operating ambient temperature:
 - 65 °C version: -40 ~ 65 °C
 - 85 °C version: -40 ~ 85 °C
 - 105 °C version: -40 ~ 105 °C

Certification

- RF certification: See [certificates](#)
- Green certification: RoHS/REACH

Test

- HTOL/HTSL/uHAST/TCT/ESD

1.2 Description

ESP32-S3-WROOM-1 and ESP32-S3-WROOM-1U are two powerful, generic Wi-Fi + Bluetooth LE MCU modules that are built around the ESP32-S3 series of SoCs. On top of a rich set of peripherals, the acceleration for neural network computing and signal processing workloads provided by the SoC make the modules an ideal choice for a wide variety of application scenarios related to AI and Artificial Intelligence of Things (AIoT), such as wake word detection, speech commands recognition, face detection and recognition, smart home, smart appliances, smart control panel, smart speaker, etc.

ESP32-S3-WROOM-1 comes with a PCB antenna. ESP32-S3-WROOM-1U comes with an external antenna connector. A wide selection of module variants are available for customers as shown in Table 1 and 2. Among the module variants, those embed ESP32-S3R8 operate at $-40 \sim 65$ °C ambient temperature, ESP32-S3-WROOM-1-H4 and ESP32-S3-WROOM-1U-H4 operate at $-40 \sim 105$ °C ambient temperature, and other module variants operate at $-40 \sim 85$ °C ambient temperature. Please note that for R8 series modules (8-line PSRAM embedded), if the PSRAM ECC function is enabled, the maximum ambient temperature can be improved to 85 °C, while the usable size of PSRAM will be reduced by 1/16.

Table 1: ESP32-S3-WROOM-1 Series Comparison¹

| Ordering Code | Flash | PSRAM ² | Ambient Temp. ³ (°C) | Size ⁴ (mm) |
|------------------------|------------------|--------------------|------------------------------------|-------------------------------|
| ESP32-S3-WROOM-1-N4 | 4 MB (Quad SPI) | - | $-40 \sim 85$ | 18.0 × 25.5 × 3.1 |
| ESP32-S3-WROOM-1-N8 | 8 MB (Quad SPI) | - | $-40 \sim 85$ | |
| ESP32-S3-WROOM-1-N16 | 16 MB (Quad SPI) | - | $-40 \sim 85$ | |
| ESP32-S3-WROOM-1-H4 | 4 MB (Quad SPI) | - | $-40 \sim 105$ | |
| ESP32-S3-WROOM-1-N4R2 | 4 MB (Quad SPI) | 2 MB (Quad SPI) | $-40 \sim 85$ | |
| ESP32-S3-WROOM-1-N8R2 | 8 MB (Quad SPI) | 2 MB (Quad SPI) | $-40 \sim 85$ | |
| ESP32-S3-WROOM-1-N16R2 | 16 MB (Quad SPI) | 2 MB (Quad SPI) | $-40 \sim 85$ | |
| ESP32-S3-WROOM-1-N4R8 | 4 MB (Quad SPI) | 8 MB (Octal SPI) | $-40 \sim 65$ | |
| ESP32-S3-WROOM-1-N8R8 | 8 MB (Quad SPI) | 8 MB (Octal SPI) | $-40 \sim 65$ | |
| ESP32-S3-WROOM-1-N16R8 | 16 MB (Quad SPI) | 8 MB (Octal SPI) | $-40 \sim 65$ | |

¹ This table shares the same notes presented in Table 2 below.

Table 2: ESP32-S3-WROOM-1U Series Comparison

| Ordering Code | Flash ² | PSRAM | Ambient Temp. ³ (°C) | Size ⁴ (mm) |
|-------------------------|--------------------|------------------|------------------------------------|-------------------------------|
| ESP32-S3-WROOM-1U-N4 | 4 MB (Quad SPI) | - | $-40 \sim 85$ | 18.0 × 19.2 × 3.2 |
| ESP32-S3-WROOM-1U-N8 | 8 MB (Quad SPI) | - | $-40 \sim 85$ | |
| ESP32-S3-WROOM-1U-N16 | 16 MB (Quad SPI) | - | $-40 \sim 85$ | |
| ESP32-S3-WROOM-1U-H4 | 4 MB (Quad SPI) | - | $-40 \sim 105$ | |
| ESP32-S3-WROOM-1U-N4R2 | 4 MB (Quad SPI) | 2 MB (Quad SPI) | $-40 \sim 85$ | |
| ESP32-S3-WROOM-1U-N8R2 | 8 MB (Quad SPI) | 2 MB (Quad SPI) | $-40 \sim 85$ | |
| ESP32-S3-WROOM-1U-N16R2 | 16 MB (Quad SPI) | 2 MB (Quad SPI) | $-40 \sim 85$ | |
| ESP32-S3-WROOM-1U-N4R8 | 4 MB (Quad SPI) | 8 MB (Octal SPI) | $-40 \sim 65$ | |
| ESP32-S3-WROOM-1U-N8R8 | 8 MB (Quad SPI) | 8 MB (Octal SPI) | $-40 \sim 65$ | |
| ESP32-S3-WROOM-1U-N16R8 | 16 MB (Quad SPI) | 8 MB (Octal SPI) | $-40 \sim 65$ | |

² The modules use PSRAM integrated in the chip's package.

³ Ambient temperature specifies the recommended temperature range of the environment immediately outside the Espressif module.

⁴ For details, refer to Section [7.1 Physical Dimensions](#).

At the core of the modules is an ESP32-S3 series of SoC *, an Xtensa® 32-bit LX7 CPU that operates at up to 240 MHz. You can power off the CPU and make use of the low-power co-processor to constantly monitor the peripherals for changes or crossing of thresholds.

ESP32-S3 integrates a rich set of peripherals including SPI, LCD, Camera interface, UART, I2C, I2S, remote control, pulse counter, LED PWM, USB Serial/JTAG controller, MCPWM, SDIO host, GDMA, TWAI® controller (compatible with ISO 11898-1), ADC, touch sensor, temperature sensor, timers and watchdogs, as well as up to 45 GPIOs. It also includes a full-speed USB 2.0 On-The-Go (OTG) interface to enable USB communication.

Note:

* For more information on ESP32-S3 series of SoCs, please refer to [ESP32-S3 Series Datasheet](#).

1.3 Applications

- Generic Low-power IoT Sensor Hub
- Generic Low-power IoT Data Loggers
- Cameras for Video Streaming
- Over-the-top (OTT) Devices
- USB Devices
- Speech Recognition
- Image Recognition
- Mesh Network
- Home Automation
- Smart Building
- Industrial Automation
- Smart Agriculture
- Audio Applications
- Health Care Applications
- Wi-Fi-enabled Toys
- Wearable Electronics
- Retail & Catering Applications

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2 Block Diagram

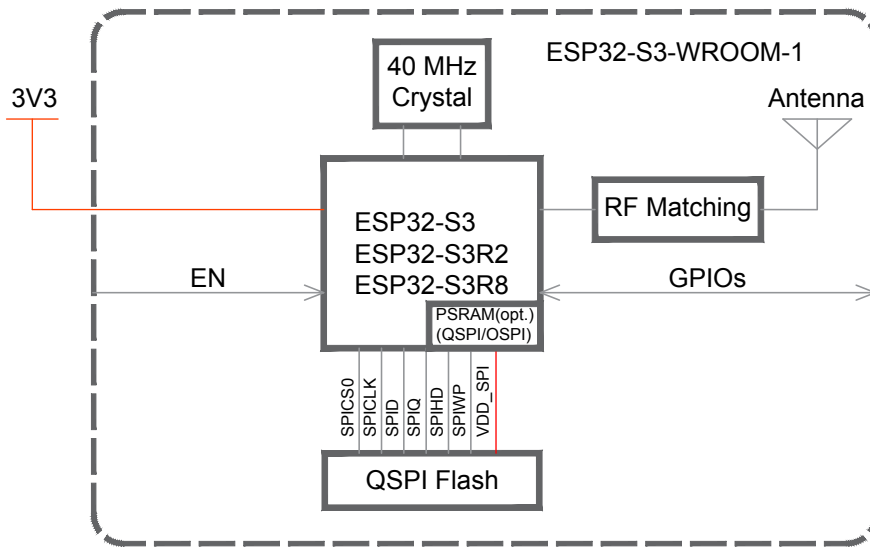


Figure 1: ESP32-S3-WROOM-1 Block Diagram

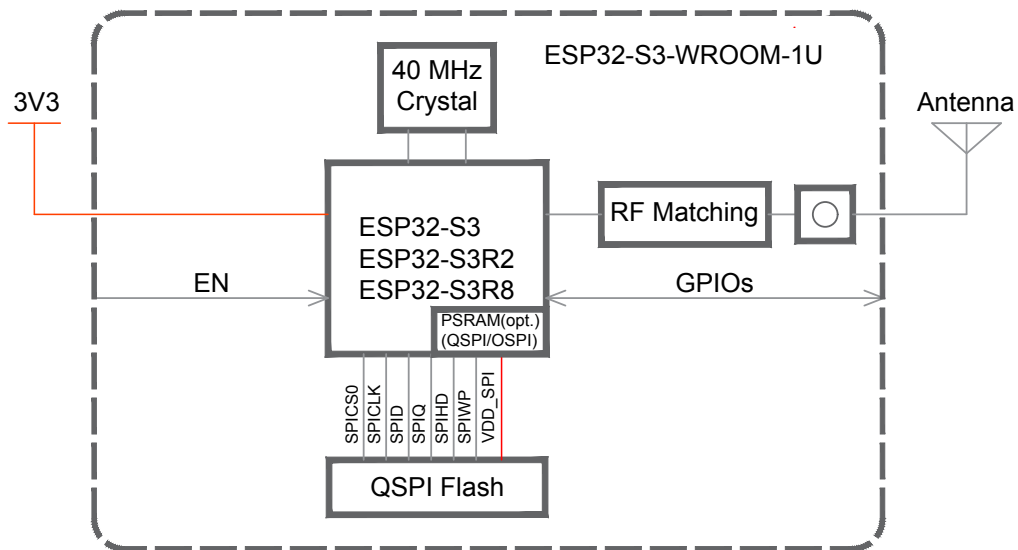


Figure 2: ESP32-S3-WROOM-1U Block Diagram

3 Pin Definitions

3.1 Pin Layout

The pin diagram below shows the approximate location of pins on the module. For the actual diagram drawn to scale, please refer to Figure 7.1 *Physical Dimensions*.

The pin diagram is applicable for ESP32-S3-WROOM-1 and ESP32-S3-WROOM-1U, but the latter has no keepout zone.

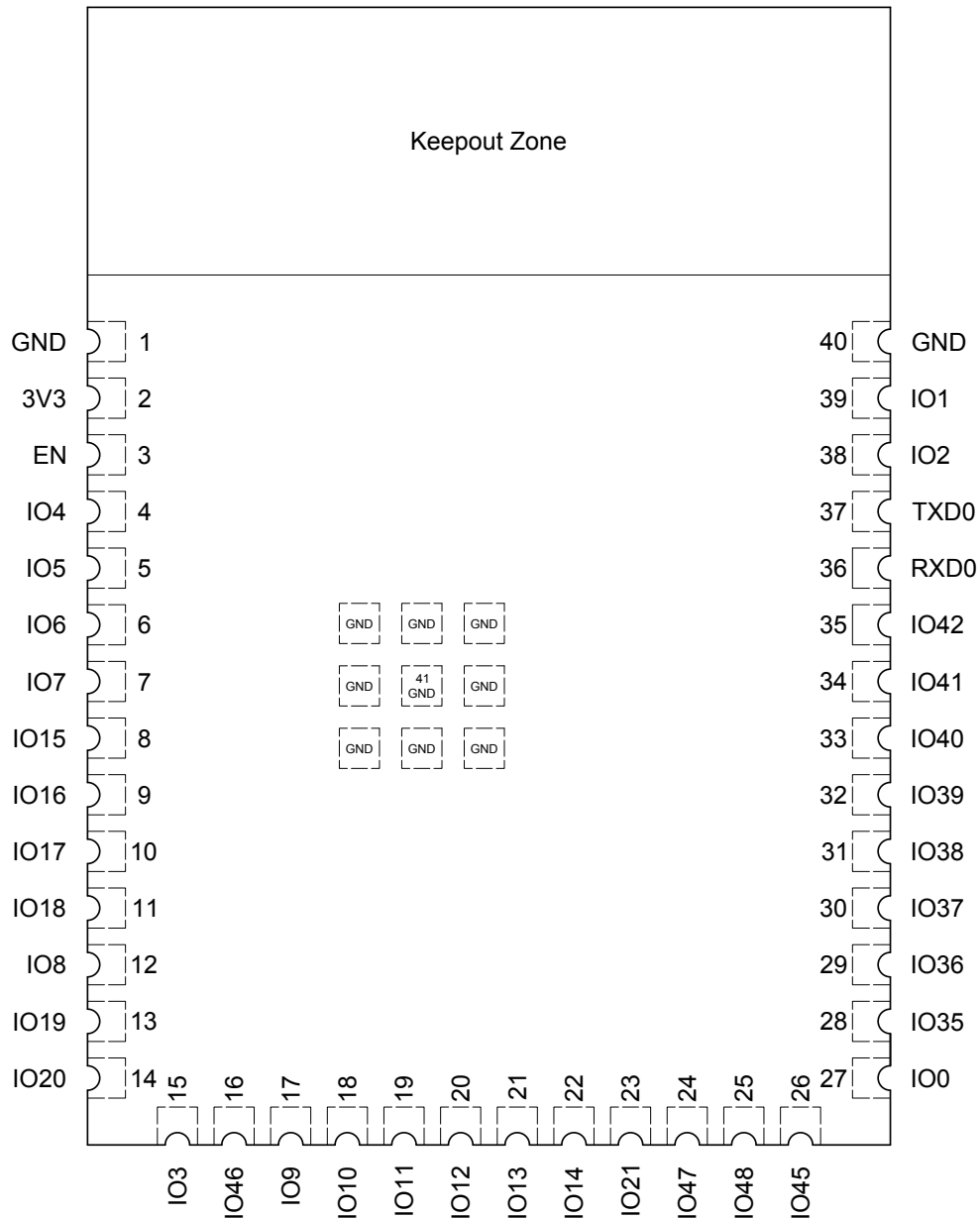


Figure 3: Pin Layout (Top View)

3.2 Pin Description

The module has 41 pins. See pin definitions in Table 3 *Pin Definitions*.

For explanations of pin names and function names, as well as configurations of peripheral pins, please refer to [ESP32-S3 Series Datasheet](#).

Table 3: Pin Definitions

| Name | No. | Type ^a | Function |
|-------------------|-----|-------------------|--|
| GND | 1 | P | GND |
| 3V3 | 2 | P | Power supply |
| EN | 3 | I | High: on, enables the chip. Low: off, the chip powers off. Note: Do not leave the EN pin floating. |
| IO4 | 4 | I/O/T | RTC_GPIO4, GPIO4 , TOUCH4, ADC1_CH3 |
| IO5 | 5 | I/O/T | RTC_GPIO5, GPIO5 , TOUCH5, ADC1_CH4 |
| IO6 | 6 | I/O/T | RTC_GPIO6, GPIO6 , TOUCH6, ADC1_CH5 |
| IO7 | 7 | I/O/T | RTC_GPIO7, GPIO7 , TOUCH7, ADC1_CH6 |
| IO15 | 8 | I/O/T | RTC_GPIO15, GPIO15 , U0RTS, ADC2_CH4, XTAL_32K_P |
| IO16 | 9 | I/O/T | RTC_GPIO16, GPIO16 , U0CTS, ADC2_CH5, XTAL_32K_N |
| IO17 | 10 | I/O/T | RTC_GPIO17, GPIO17 , U1TXD, ADC2_CH6 |
| IO18 | 11 | I/O/T | RTC_GPIO18, GPIO18 , U1RXD, ADC2_CH7, CLK_OUT3 |
| IO8 | 12 | I/O/T | RTC_GPIO8, GPIO8 , TOUCH8, ADC1_CH7, SUBSPICS1 |
| IO19 | 13 | I/O/T | RTC_GPIO19, GPIO19, U1RTS, ADC2_CH8, CLK_OUT2, USB_D- |
| IO20 | 14 | I/O/T | RTC_GPIO20, GPIO20, U1CTS, ADC2_CH9, CLK_OUT1, USB_D+ |
| IO3 | 15 | I/O/T | RTC_GPIO3, GPIO3 , TOUCH3, ADC1_CH2 |
| IO46 | 16 | I/O/T | GPIO46 |
| IO9 | 17 | I/O/T | RTC_GPIO9, GPIO9 , TOUCH9, ADC1_CH8, FSPIHD, SUBSPIHD |
| IO10 | 18 | I/O/T | RTC_GPIO10, GPIO10 , TOUCH10, ADC1_CH9, FSPICS0, FSPIIO4, SUBSPICS0 |
| IO11 | 19 | I/O/T | RTC_GPIO11, GPIO11 , TOUCH11, ADC2_CH0, FSPID, FSPIIO5, SUBSPID |
| IO12 | 20 | I/O/T | RTC_GPIO12, GPIO12 , TOUCH12, ADC2_CH1, FSPICLK, FSPIIO6, SUBSPICLK |
| IO13 | 21 | I/O/T | RTC_GPIO13, GPIO13 , TOUCH13, ADC2_CH2, FSPIQ, FSPIIO7, SUBSPIQ |
| IO14 | 22 | I/O/T | RTC_GPIO14, GPIO14 , TOUCH14, ADC2_CH3, FSPIWP, FSPIDQS, SUBSPIWP |
| IO21 | 23 | I/O/T | RTC_GPIO21, GPIO21 |
| IO47 | 24 | I/O/T | SPICLK_P_DIFF, GPIO47 , SUBSPICLK_P_DIFF |
| IO48 | 25 | I/O/T | SPICLK_N_DIFF, GPIO48 , SUBSPICLK_N_DIFF |
| IO45 | 26 | I/O/T | GPIO45 |
| IO0 | 27 | I/O/T | RTC_GPIO0, GPIO0 |
| IO35 ^b | 28 | I/O/T | SPIIO6, GPIO35 , FSPID, SUBSPID |
| IO36 ^b | 29 | I/O/T | SPIIO7, GPIO36 , FSPICLK, SUBSPICLK |

Cont'd on next page

Table 3 – cont'd from previous page

| Name | No. | Type ^a | Function |
|-------------------|-----|-------------------|--|
| IO37 ^b | 30 | I/O/T | SPIDQS, GPIO37 , FSPIQ, SUBSPIQ |
| IO38 | 31 | I/O/T | GPIO38 , FSPIWP, SUBSPIWP |
| IO39 | 32 | I/O/T | MTCK , GPIO39, CLK_OUT3, SUBSPICS1 |
| IO40 | 33 | I/O/T | MTDO , GPIO40, CLK_OUT2 |
| IO41 | 34 | I/O/T | MTDI , GPIO41, CLK_OUT1 |
| IO42 | 35 | I/O/T | MTMS , GPIO42 |
| RXD0 | 36 | I/O/T | U0RXD , GPIO44, CLK_OUT2 |
| TXD0 | 37 | I/O/T | U0TXD , GPIO43, CLK_OUT1 |
| IO2 | 38 | I/O/T | RTC_GPIO2, GPIO2 , TOUCH2, ADC1_CH1 |
| IO1 | 39 | I/O/T | RTC_GPIO1, GPIO1 , TOUCH1, ADC1_CH0 |
| GND | 40 | P | GND |
| EPAD | 41 | P | GND |

^a P: power supply; I: input; O: output; T: high impedance. Pin functions in bold font are the default pin functions. For pin 28 ~ 30, the default function is decided by eFuse bit.

^b In module variants that have embedded OSPI PSRAM, i.e., that embed ESP32-S3R8, pins IO35, IO36, and IO37 connect to the OSPI PSRAM and are not available for other uses.

3.3 Strapping Pins

Note:

The content below is excerpted from [ESP32-S3 Series Datasheet](#) > Section *Strapping Pins*. For the strapping pin mapping between the chip and modules, please refer to Chapter 5 *Module Schematics*.

At each startup or reset, a module requires some initial configuration parameters, such as in which boot mode to load the module, voltage of flash memory, etc. These parameters are passed over via the strapping pins. After reset, the strapping pins operate as regular IO pins.

The parameters controlled by the given strapping pins at module reset are as follows:

- **Chip boot mode** – GPIO0 and GPIO46
- **VDD_SPI voltage** – GPIO45
- **ROM messages printing** – GPIO46
- **JTAG signal source** – GPIO3

GPIO0, GPIO45, and GPIO46 are connected to the chip's internal weak pull-up/pull-down resistors at chip reset. These resistors determine the default bit values of the strapping pins. Also, these resistors determine the bit values if the strapping pins are connected to an external high-impedance circuit.

Table 4: Default Configuration of Strapping Pins

| Strapping Pin | Default Configuration | Bit Value |
|---------------|-----------------------|-----------|
| GPIO0 | Pull-up | 1 |
| GPIO3 | Floating | – |
| GPIO45 | Pull-down | 0 |
| GPIO46 | Pull-down | 0 |

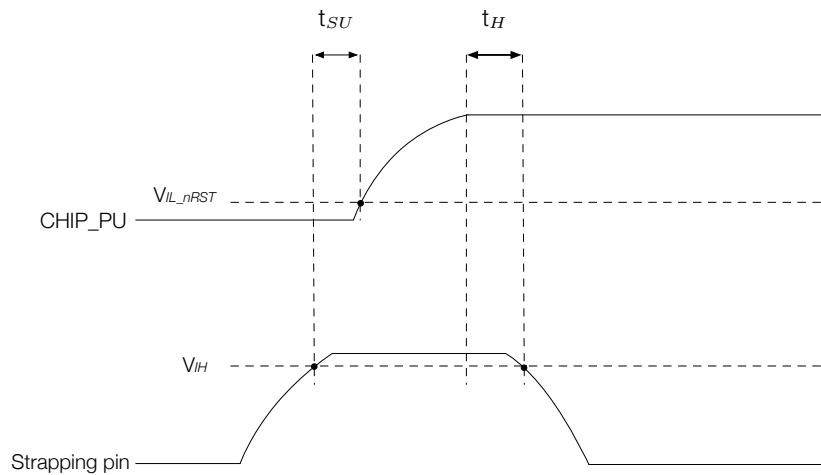
To change the bit values, the strapping pins should be connected to external pull-down/pull-up resistances. If the ESP32-S3 is used as a device by a host MCU, the strapping pin voltage levels can also be controlled by the host MCU.

All strapping pins have latches. At system reset, the latches sample the bit values of their respective strapping pins and store them until the chip is powered down or shut down. The states of latches cannot be changed in any other way. It makes the strapping pin values available during the entire chip operation, and the pins are freed up to be used as regular IO pins after reset.

Regarding the timing requirements for the strapping pins, there are such parameters as *setup time* and *hold time*. For more information, see Table 5 and Figure 4.

Table 5: Description of Timing Parameters for the Strapping Pins

| Parameter | Description | Min (ms) |
|-----------|---|----------|
| t_{SU} | <i>Setup time</i> is the time reserved for the power rails to stabilize before the CHIP_PU pin is pulled high to activate the chip. | 0 |
| t_H | <i>Hold time</i> is the time reserved for the chip to read the strapping pin values after CHIP_PU is already high and before these pins start operating as regular IO pins. | 3 |

**Figure 4: Visualization of Timing Parameters for the Strapping Pins**

3.3.1 Chip Boot Mode Control

GPIO0 and GPIO46 control the boot mode after the reset is released. See [Table 6 Chip Boot Mode Control](#).

Table 6: Chip Boot Mode Control

| Boot Mode | GPIO0 | GPIO46 |
|----------------------------------|-------------|---------------|
| Default Configuration | 1 (Pull-up) | 0 (Pull-down) |
| SPI Boot (default) | 1 | Any value |
| Download Boot | 0 | 0 |
| Invalid combination ¹ | 0 | 1 |

¹ This combination triggers unexpected behavior and should be avoided.

3.3.2 VDD_SPI Voltage Control

Depending on the value of EFUSE_VDD_SPI_FORCE, the voltage can be controlled in two ways.

Table 7: VDD_SPI Voltage Control

| EFUSE_VDD_SPI_FORCE | GPIO45 | eFuse ¹ | Voltage | VDD_SPI power source ² |
|---------------------|---------|--------------------|---------|-----------------------------------|
| 0 | 0 | Ignored | 3.3 V | VDD3P3_RTC via R _{SPI} |
| | 1 | | 1.8 V | Flash Voltage Regulator |
| 1 | Ignored | 0 | 1.8 V | Flash Voltage Regulator |
| | | 1 | 3.3 V | VDD3P3_RTC via R _{SPI} |

¹ eFuse: EFUSE_VDD_SPI_TIEH

² See [ESP32-S3 Series Datasheet](#) > Section *Power Scheme*

3.3.3 ROM Messages Printing Control

During boot process the messages by the ROM code can be printed to:

- (Default) UART and USB Serial/JTAG controller.
- USB Serial/JTAG controller.
- UART.

The ROM messages printing to UART or USB Serial/JTAG controller can be respectively disabled by configuring registers and eFuse. For detailed information, please refer to [ESP32-S3 Technical Reference Manual](#) > Chapter *Chip Boot Control*.

3.3.4 JTAG Signal Source Control

The strapping pin GPIO3 can be used to control the source of JTAG signals during the early boot process. This pin does not have any internal pull resistors and the strapping value must be controlled by the external circuit that cannot be in a high impedance state.

As Table 8 shows, GPIO3 is used in combination with EFUSE_DIS_PAD_JTAG, EFUSE_DIS_USB_JTAG, and EFUSE_STRAP_JTAG_SEL.

Table 8: JTAG Signal Source Control

| eFuse 1 ^a | eFuse 2 ^b | eFuse 3 ^c | GPIO3 | JTAG Signal Source |
|----------------------|----------------------|----------------------|---------|--------------------------------------|
| 0 | 0 | 0 | Ignored | USB Serial/JTAG Controller |
| | | 1 | 0 | JTAG pins MTDI, MTCK, MTMS, and MTDO |
| | | | 1 | USB Serial/JTAG Controller |
| 0 | 1 | Ignored | Ignored | JTAG pins MTDI, MTCK, MTMS, and MTDO |
| 1 | 0 | Ignored | Ignored | USB Serial/JTAG Controller |
| 1 | 1 | Ignored | Ignored | JTAG is disabled |

^a eFuse 1: EFUSE_DIS_PAD_JTAG

^b eFuse 2: EFUSE_DIS_USB_JTAG

^c eFuse 3: EFUSE_STRAP_JTAG_SEL

4 Electrical Characteristics

4.1 Absolute Maximum Ratings

Stresses above those listed in Table 9 *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under Table 10 *Recommended Operating Conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

Table 9: Absolute Maximum Ratings

| Symbol | Parameter | Min | Max | Unit |
|--------------------|----------------------|------|-----|------|
| VDD33 | Power supply voltage | -0.3 | 3.6 | V |
| T _{STORE} | Storage temperature | -40 | 105 | °C |

4.2 Recommended Operating Conditions

Table 10: Recommended Operating Conditions

| Symbol | Parameter | Min | Typ | Max | Unit | |
|------------------|--|----------------|-----|-----|------|----|
| VDD33 | Power supply voltage | 3.0 | 3.3 | 3.6 | V | |
| I _{VDD} | Current delivered by external power supply | 0.5 | — | — | A | |
| T _A | Operating ambient temperature | 65 °C version | -40 | — | 65 | °C |
| | | 85 °C version | | | 85 | |
| | | 105 °C version | | | 105 | |

4.3 DC Characteristics (3.3 V, 25 °C)

Table 11: DC Characteristics (3.3 V, 25 °C)

| Symbol | Parameter | Min | Typ | Max | Unit |
|------------------------------|--|-------------------------|-----|-------------------------|------|
| C _{IN} | Pin capacitance | — | 2 | — | pF |
| V _{IH} | High-level input voltage | 0.75 × VDD ¹ | — | VDD ¹ + 0.3 | V |
| V _{IL} | Low-level input voltage | -0.3 | — | 0.25 × VDD ¹ | V |
| I _{IH} | High-level input current | — | — | 50 | nA |
| I _{IL} | Low-level input current | — | — | 50 | nA |
| V _{OH} ² | High-level output voltage | 0.8 × VDD ¹ | — | — | V |
| V _{OL} ² | Low-level output voltage | — | — | 0.1 × VDD ¹ | V |
| I _{OH} | High-level source current (VDD ¹ = 3.3 V, V _{OH} ≥ 2.64 V, PAD_DRIVER = 3) | — | 40 | — | mA |
| I _{OL} | Low-level sink current (VDD ¹ = 3.3 V, V _{OL} = 0.495 V, PAD_DRIVER = 3) | — | 28 | — | mA |
| R _{PU} | Internal weak pull-up resistor | — | 45 | — | kΩ |
| R _{PD} | Internal weak pull-down resistor | — | 45 | — | kΩ |

Cont'd on next page

Table 11 – cont'd from previous page

| Symbol | Parameter | Min | Typ | Max | Unit |
|----------------|---|---------------------|-----|---------------------|------|
| V_{IH_nRST} | Chip reset release voltage (EN voltage is within the specified range) | $0.75 \times VDD^1$ | — | $VDD^1 + 0.3$ | V |
| V_{IL_nRST} | Chip reset voltage (EN voltage is within the specified range) | -0.3 | — | $0.25 \times VDD^1$ | V |

¹ VDD is the I/O voltage for pins of a particular power domain.

² V_{OH} and V_{OL} are measured using high-impedance load.

4.4 Current Consumption Characteristics

4.4.1 RF Current Consumption in Active Mode

With the use of advanced power-management technologies, the module can switch between different power modes. For details on different power modes, please refer to Section *Low Power Management* in [ESP32-S3 Series Datasheet](#).

Table 12: Current Consumption Depending on RF Modes

| Work mode | Description | Peak (mA) | |
|---------------------|-------------|---------------------------------|-----|
| Active (RF working) | TX | 802.11b, 1 Mbps, @20.5 dBm | 355 |
| | | 802.11g, 54 Mbps, @18 dBm | 297 |
| | | 802.11n, HT20, MCS 7, @17.5 dBm | 286 |
| | | 802.11n, HT40, MCS 7, @17 dBm | 285 |
| | RX | 802.11b/g/n, HT20 | 95 |
| | | 802.11n, HT40 | 97 |

¹ The current consumption measurements are taken with a 3.3 V supply at 25 °C of ambient temperature at the RF port. All transmitters' measurements are based on a 100% duty cycle.

² The current consumption figures for in RX mode are for cases when the peripherals are disabled and the CPU idle.

Note:

The content below is excerpted from *Section Power Consumption in Other Modes* in [ESP32-S3 Series Datasheet](#).

4.4.2 Current Consumption in Other Modes

Please note that if the chip embedded has in-package PSRAM, the current consumption of the module might be higher compared to the measurements below.

Table 13: Current Consumption in Modem-sleep Mode

| Work mode | Frequency (MHz) | Description | Typ ¹ (mA) | Typ ² (mA) |
|--------------------------|-----------------|--|-----------------------|-----------------------|
| Modem-sleep ³ | 40 | WAITI (Dual core in idle state) | 13.2 | 18.8 |
| | | Single core running 32-bit data access instructions, the other core in idle state | 16.2 | 21.8 |
| | | Dual core running 32-bit data access instructions | 18.7 | 24.4 |
| | | Single core running 128-bit data access instructions, the other core in idle state | 19.9 | 25.4 |
| | | Dual core running 128-bit data access instructions | 23.0 | 28.8 |
| | 80 | WAITI | 22.0 | 36.1 |
| | | Single core running 32-bit data access instructions, the other core in idle state | 28.4 | 42.6 |
| | | Dual core running 32-bit data access instructions | 33.1 | 47.3 |
| | | Single core running 128-bit data access instructions, the other core in idle state | 35.1 | 49.6 |
| | | Dual core running 128-bit data access instructions | 41.8 | 56.3 |
| | 160 | WAITI | 27.6 | 42.3 |
| | | Single core running 32-bit data access instructions, the other core in idle state | 39.9 | 54.6 |
| | | Dual core running 32-bit data access instructions | 49.6 | 64.1 |
| | | Single core running 128-bit data access instructions, the other core in idle state | 54.4 | 69.2 |
| | | Dual core running 128-bit data access instructions | 66.7 | 81.1 |
| | 240 | WAITI | 32.9 | 47.6 |
| | | Single core running 32-bit data access instructions, the other core in idle state | 51.2 | 65.9 |
| | | Dual core running 32-bit data access instructions | 66.2 | 81.3 |
| | | Single core running 128-bit data access instructions, the other core in idle state | 72.4 | 87.9 |
| | | Dual core running 128-bit data access instructions | 91.7 | 107.9 |

¹ Current consumption when all peripheral clocks are **disabled**.

² Current consumption when all peripheral clocks are **enabled**. In practice, the current consumption might be different depending on which peripherals are enabled.

³ In Modem-sleep mode, Wi-Fi is clock gated, and the current consumption might be higher when accessing flash. For a flash rated at 80 Mbit/s, in SPI 2-line mode the consumption is 10 mA.

Table 14: Current Consumption in Low-Power Modes

| Work mode | Description | Typ (μ A) |
|--------------------------|---|----------------|
| Light-sleep ¹ | VDD_SPI and Wi-Fi are powered down, and all GPIOs are high-impedance. | 240 |
| Deep-sleep | RTC memory and RTC peripherals are powered up. | 8 |
| | RTC memory is powered up. RTC peripherals are powered down. | 7 |

| | | |
|-----------|---|---|
| Power off | CHIP_PU is set to low level. The chip is shut down. | 1 |
|-----------|---|---|

¹ In Light-sleep mode, all related SPI pins are pulled up. For chips embedded with PSRAM, please add corresponding PSRAM consumption values, e.g., 140 μ A for 8 MB 8-line PSRAM (3.3 V), 200 μ A for 8 MB 8-line PSRAM (1.8 V) and 40 μ A for 2 MB 4-line PSRAM (3.3 V).

4.5 Wi-Fi RF Characteristics

4.5.1 Wi-Fi RF Standards

Table 15: Wi-Fi RF Standards

| Name | | Description |
|--|--------|--|
| Center frequency range of operating channel ¹ | | 2412 ~ 2484 MHz |
| Wi-Fi wireless standard | | IEEE 802.11b/g/n |
| Data rate | 20 MHz | 11b: 1, 2, 5.5 and 11 Mbps 11g: 6, 9, 12, 18, 24, 36, 48, 54 Mbps 11n: MCS0-7, 72.2 Mbps (Max) |
| | 40 MHz | 11n: MCS0-7, 150 Mbps (Max) |
| Antenna type | | PCB antenna, external antenna connector ² |

¹ Device should operate in the center frequency range allocated by regional regulatory authorities. Target center frequency range is configurable by software.

² For the modules that use external antenna connectors, the output impedance is 50 Ω . For other modules without external antenna connectors, the output impedance is irrelevant.

4.5.2 Wi-Fi RF Transmitter (TX) Specifications

Target TX power is configurable based on device or certification requirements. The default characteristics are provided in Table 16 *TX Power with Spectral Mask and EVM Meeting 802.11 Standards*.

Table 16: TX Power with Spectral Mask and EVM Meeting 802.11 Standards

| Rate | Min (dBm) | Typ (dBm) | Max (dBm) |
|----------------------|-----------|-----------|-----------|
| 802.11b, 1 Mbps | — | 20.5 | — |
| 802.11b, 11 Mbps | — | 20.5 | — |
| 802.11g, 6 Mbps | — | 20.0 | — |
| 802.11g, 54 Mbps | — | 18.0 | — |
| 802.11n, HT20, MCS 0 | — | 19.0 | — |
| 802.11n, HT20, MCS 7 | — | 17.5 | — |
| 802.11n, HT40, MCS 0 | — | 18.5 | — |
| 802.11n, HT40, MCS 7 | — | 17.0 | — |

Table 17: TX EVM Test

| Rate | Min (dB) | Typ (dB) | SL ¹ (dB) |
|---------------------------------|----------|----------|----------------------|
| 802.11b, 1 Mbps, @20.5 dBm | — | -24.5 | -10 |
| 802.11b, 11 Mbps, @20.5 dBm | — | -24.5 | -10 |
| 802.11g, 6 Mbps, @20 dBm | — | -23.0 | -5 |
| 802.11g, 54 Mbps, @18 dBm | — | -29.5 | -25 |
| 802.11n, HT20, MCS 0, @19 dBm | — | -24.0 | -5 |
| 802.11n, HT20, MCS 7, @17.5 dBm | — | -30.5 | -27 |
| 802.11n, HT40, MCS 0, @18.5 dBm | — | -25.0 | -5 |
| 802.11n, HT40, MCS 7, @17 dBm | — | -30.0 | -27 |

¹ SL stands for standard limit value.

4.5.3 Wi-Fi RF Receiver (RX) Specifications

Table 18: RX Sensitivity

| Rate | Min (dBm) | Typ (dBm) | Max (dBm) |
|----------------------|-----------|-----------|-----------|
| 802.11b, 1 Mbps | — | -98.2 | — |
| 802.11b, 2 Mbps | — | -95.6 | — |
| 802.11b, 5.5 Mbps | — | -92.8 | — |
| 802.11b, 11 Mbps | — | -88.5 | — |
| 802.11g, 6 Mbps | — | -93.0 | — |
| 802.11g, 9 Mbps | — | -92.0 | — |
| 802.11g, 12 Mbps | — | -90.8 | — |
| 802.11g, 18 Mbps | — | -88.5 | — |
| 802.11g, 24 Mbps | — | -85.5 | — |
| 802.11g, 36 Mbps | — | -82.2 | — |
| 802.11g, 48 Mbps | — | -78.0 | — |
| 802.11g, 54 Mbps | — | -76.2 | — |
| 802.11n, HT20, MCS 0 | — | -93.0 | — |
| 802.11n, HT20, MCS 1 | — | -90.6 | — |
| 802.11n, HT20, MCS 2 | — | -88.4 | — |
| 802.11n, HT20, MCS 3 | — | -84.8 | — |
| 802.11n, HT20, MCS 4 | — | -81.6 | — |
| 802.11n, HT20, MCS 5 | — | -77.4 | — |
| 802.11n, HT20, MCS 6 | — | -75.6 | — |
| 802.11n, HT20, MCS 7 | — | -74.2 | — |
| 802.11n, HT40, MCS 0 | — | -90.0 | — |
| 802.11n, HT40, MCS 1 | — | -87.5 | — |
| 802.11n, HT40, MCS 2 | — | -85.0 | — |
| 802.11n, HT40, MCS 3 | — | -82.0 | — |

Cont'd on next page

Table 18 – cont'd from previous page

| Rate | Min (dBm) | Typ (dBm) | Max (dBm) |
|----------------------|-----------|-----------|-----------|
| 802.11n, HT40, MCS 4 | — | -78.5 | — |
| 802.11n, HT40, MCS 5 | — | -74.4 | — |
| 802.11n, HT40, MCS 6 | — | -72.5 | — |
| 802.11n, HT40, MCS 7 | — | -71.2 | — |

Table 19: Maximum RX Level

| Rate | Min (dBm) | Typ (dBm) | Max (dBm) |
|----------------------|-----------|-----------|-----------|
| 802.11b, 1 Mbps | — | 5 | — |
| 802.11b, 11 Mbps | — | 5 | — |
| 802.11g, 6 Mbps | — | 5 | — |
| 802.11g, 54 Mbps | — | 0 | — |
| 802.11n, HT20, MCS 0 | — | 5 | — |
| 802.11n, HT20, MCS 7 | — | 0 | — |
| 802.11n, HT40, MCS 0 | — | 5 | — |
| 802.11n, HT40, MCS 7 | — | 0 | — |

Table 20: RX Adjacent Channel Rejection

| Rate | Min (dB) | Typ (dB) | Max (dB) |
|----------------------|----------|----------|----------|
| 802.11b, 1 Mbps | — | 35 | — |
| 802.11b, 11 Mbps | — | 35 | — |
| 802.11g, 6 Mbps | — | 31 | — |
| 802.11g, 54 Mbps | — | 14 | — |
| 802.11n, HT20, MCS 0 | — | 31 | — |
| 802.11n, HT20, MCS 7 | — | 13 | — |
| 802.11n, HT40, MCS 0 | — | 19 | — |
| 802.11n, HT40, MCS 7 | — | 8 | — |

4.6 Bluetooth LE Radio

Table 21: Bluetooth LE Frequency

| Parameter | Min (MHz) | Typ (MHz) | Max (MHz) |
|---------------------------------------|-----------|-----------|-----------|
| Center frequency of operating channel | 2402 | — | 2480 |

4.6.1 Bluetooth LE RF Transmitter (TX) Specifications

Table 22: Transmitter Characteristics - Bluetooth LE 1 Mbps

| Parameter | Description | Min | Typ | Max | Unit |
|------------------------------------|--|--------|--------|-------|------|
| RF transmit power | RF power control range | -24.00 | 0 | 20.00 | dBm |
| | Gain control step | — | 3.00 | — | dB |
| Carrier frequency offset and drift | Max $ f_n _{n=0, 1, 2, \dots, k}$ | — | 2.50 | — | kHz |
| | Max $ f_0 - f_n $ | — | 2.00 | — | kHz |
| | Max $ f_n - f_{n-5} $ | — | 1.40 | — | kHz |
| | $ f_1 - f_0 $ | — | 1.00 | — | kHz |
| Modulation characteristics | $\Delta f_{1\text{avg}}$ | — | 249.00 | — | kHz |
| | Min $\Delta f_{2\text{max}}$ (for at least 99.9% of all $\Delta f_{2\text{max}}$) | — | 198.00 | — | kHz |
| | $\Delta f_{2\text{avg}}/\Delta f_{1\text{avg}}$ | — | 0.86 | — | — |
| In-band spurious emissions | ± 2 MHz offset | — | -37.00 | — | dBm |
| | ± 3 MHz offset | — | -42.00 | — | dBm |
| | $>\pm 3$ MHz offset | — | -44.00 | — | dBm |

Table 23: Transmitter Characteristics - Bluetooth LE 2 Mbps

| Parameter | Description | Min | Typ | Max | Unit |
|------------------------------------|--|--------|--------|-------|------|
| RF transmit power | RF power control range | -24.00 | 0 | 20.00 | dBm |
| | Gain control step | — | 3.00 | — | dB |
| Carrier frequency offset and drift | Max $ f_n _{n=0, 1, 2, \dots, k}$ | — | 2.50 | — | kHz |
| | Max $ f_0 - f_n $ | — | 2.00 | — | kHz |
| | Max $ f_n - f_{n-5} $ | — | 1.40 | — | kHz |
| | $ f_1 - f_0 $ | — | 1.00 | — | kHz |
| Modulation characteristics | $\Delta f_{1\text{avg}}$ | — | 499.00 | — | kHz |
| | Min $\Delta f_{2\text{max}}$ (for at least 99.9% of all $\Delta f_{2\text{max}}$) | — | 416.00 | — | kHz |
| | $\Delta f_{2\text{avg}}/\Delta f_{1\text{avg}}$ | — | 0.89 | — | — |
| In-band spurious emissions | ± 4 MHz offset | — | -42.00 | — | dBm |
| | ± 5 MHz offset | — | -44.00 | — | dBm |
| | $>\pm 5$ MHz offset | — | -47.00 | — | dBm |

Table 24: Transmitter Characteristics - Bluetooth LE 125 Kbps

| Parameter | Description | Min | Typ | Max | Unit |
|------------------------------------|-----------------------------------|--------|------|-------|------|
| RF transmit power | RF power control range | -24.00 | 0 | 20.00 | dBm |
| | Gain control step | — | 3.00 | — | dB |
| Carrier frequency offset and drift | Max $ f_n _{n=0, 1, 2, \dots, k}$ | — | 0.80 | — | kHz |
| | Max $ f_0 - f_n $ | — | 1.00 | — | kHz |
| | $ f_n - f_{n-3} $ | — | 0.30 | — | kHz |

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Table 24 – cont'd from previous page

| Parameter | Description | Min | Typ | Max | Unit |
|----------------------------|--|-----|--------|-----|------|
| | $ f_0 - f_3 $ | — | 1.00 | — | kHz |
| Modulation characteristics | $\Delta f_{1\text{avg}}$ | — | 248.00 | — | kHz |
| | Min $\Delta f_{1\text{max}}$ (for at least 99.9% of all $\Delta f_{1\text{max}}$) | — | 222.00 | — | kHz |
| In-band spurious emissions | ± 2 MHz offset | — | -37.00 | — | dBm |
| | ± 3 MHz offset | — | -42.00 | — | dBm |
| | $> \pm 3$ MHz offset | — | -44.00 | — | dBm |

Table 25: Transmitter Characteristics - Bluetooth LE 500 Kbps

| Parameter | Description | Min | Typ | Max | Unit |
|------------------------------------|--|--------|--------|-------|------|
| RF transmit power | RF power control range | -24.00 | 0 | 20.00 | dBm |
| | Gain control step | — | 3.00 | — | dB |
| Carrier frequency offset and drift | Max $ f_n _{n=0, 1, 2, \dots, k}$ | — | 0.80 | — | kHz |
| | Max $ f_0 - f_n $ | — | 1.00 | — | kHz |
| | $ f_n - f_{n-3} $ | — | 0.85 | — | kHz |
| | $ f_0 - f_3 $ | — | 0.34 | — | kHz |
| Modulation characteristics | $\Delta f_{2\text{avg}}$ | — | 213.00 | — | kHz |
| | Min $\Delta f_{2\text{max}}$ (for at least 99.9% of all $\Delta f_{2\text{max}}$) | — | 196.00 | — | kHz |
| In-band spurious emissions | ± 2 MHz offset | — | -37.00 | — | dBm |
| | ± 3 MHz offset | — | -42.00 | — | dBm |
| | $> \pm 3$ MHz offset | — | -44.00 | — | dBm |

4.6.2 Bluetooth LE RF Receiver (RX) Specifications

Table 26: Receiver Characteristics - Bluetooth LE 1 Mbps

| Parameter | Description | Min | Typ | Max | Unit |
|------------------------------------|----------------|-----|-------|-----|------|
| Sensitivity @30.8% PER | — | — | -96.5 | — | dBm |
| Maximum received signal @30.8% PER | — | — | 8 | — | dBm |
| Co-channel C/I | F = F0 MHz | — | 8 | — | dB |
| Adjacent channel selectivity C/I | F = F0 + 1 MHz | — | 4 | — | dB |
| | F = F0 - 1 MHz | — | 4 | — | dB |
| | F = F0 + 2 MHz | — | -23 | — | dB |
| | F = F0 - 2 MHz | — | -23 | — | dB |
| | F = F0 + 3 MHz | — | -34 | — | dB |
| | F = F0 - 3 MHz | — | -34 | — | dB |
| | F > F0 + 3 MHz | — | -36 | — | dB |
| F > F0 - 3 MHz | — | -37 | — | dB | |
| Image frequency | — | — | -36 | — | dB |

Cont'd on next page

Table 26 – cont'd from previous page

| Parameter | Description | Min | Typ | Max | Unit |
|-------------------------------------|---------------------------------|-----|-----|-----|------|
| Adjacent channel to image frequency | $F = F_{image} + 1 \text{ MHz}$ | — | -39 | — | dB |
| | $F = F_{image} - 1 \text{ MHz}$ | — | -34 | — | dB |
| Out-of-band blocking performance | 30 MHz ~ 2000 MHz | — | -12 | — | dBm |
| | 2003 MHz ~ 2399 MHz | — | -18 | — | dBm |
| | 2484 MHz ~ 2997 MHz | — | -16 | — | dBm |
| | 3000 MHz ~ 12.75 GHz | — | -10 | — | dBm |
| Intermodulation | — | — | -29 | — | dBm |

Table 27: Receiver Characteristics - Bluetooth LE 2 Mbps

| Parameter | Description | Min | Typ | Max | Unit |
|-------------------------------------|---------------------------------|-----|-----|-----|------|
| Sensitivity @30.8% PER | — | — | -92 | — | dBm |
| Maximum received signal @30.8% PER | — | — | 3 | — | dBm |
| Co-channel C/I | $F = F_0 \text{ MHz}$ | — | 8 | — | dB |
| Adjacent channel selectivity C/I | $F = F_0 + 2 \text{ MHz}$ | — | 4 | — | dB |
| | $F = F_0 - 2 \text{ MHz}$ | — | 4 | — | dB |
| | $F = F_0 + 4 \text{ MHz}$ | — | -27 | — | dB |
| | $F = F_0 - 4 \text{ MHz}$ | — | -27 | — | dB |
| | $F = F_0 + 6 \text{ MHz}$ | — | -38 | — | dB |
| | $F = F_0 - 6 \text{ MHz}$ | — | -38 | — | dB |
| | $F > F_0 + 6 \text{ MHz}$ | — | -41 | — | dB |
| Image frequency | — | — | -27 | — | dB |
| Adjacent channel to image frequency | $F = F_{image} + 2 \text{ MHz}$ | — | -38 | — | dB |
| | $F = F_{image} - 2 \text{ MHz}$ | — | 4 | — | dB |
| Out-of-band blocking performance | 30 MHz ~ 2000 MHz | — | -15 | — | dBm |
| | 2003 MHz ~ 2399 MHz | — | -21 | — | dBm |
| | 2484 MHz ~ 2997 MHz | — | -21 | — | dBm |
| | 3000 MHz ~ 12.75 GHz | — | -9 | — | dBm |
| Intermodulation | — | — | -29 | — | dBm |

Table 28: Receiver Characteristics - Bluetooth LE 125 Kbps

| Parameter | Description | Min | Typ | Max | Unit |
|------------------------------------|---------------------------|-----|--------|-----|------|
| Sensitivity @30.8% PER | — | — | -103.5 | — | dBm |
| Maximum received signal @30.8% PER | — | — | 8 | — | dBm |
| Co-channel C/I | $F = F_0 \text{ MHz}$ | — | 4 | — | dB |
| Adjacent channel selectivity C/I | $F = F_0 + 1 \text{ MHz}$ | — | 1 | — | dB |
| | $F = F_0 - 1 \text{ MHz}$ | — | 2 | — | dB |
| | $F = F_0 + 2 \text{ MHz}$ | — | -26 | — | dB |
| | $F = F_0 - 2 \text{ MHz}$ | — | -26 | — | dB |
| | $F = F_0 + 3 \text{ MHz}$ | — | -36 | — | dB |
| | $F = F_0 - 3 \text{ MHz}$ | — | -39 | — | dB |

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Table 28 – cont'd from previous page

| Parameter | Description | Min | Typ | Max | Unit |
|-------------------------------------|---------------------------------|-----|-----|-----|------|
| | $F > F_0 + 3 \text{ MHz}$ | — | -42 | — | dB |
| | $F > F_0 - 3 \text{ MHz}$ | — | -43 | — | dB |
| Image frequency | — | — | -42 | — | dB |
| Adjacent channel to image frequency | $F = F_{image} + 1 \text{ MHz}$ | — | -43 | — | dB |
| | $F = F_{image} - 1 \text{ MHz}$ | — | -36 | — | dB |

Table 29: Receiver Characteristics - Bluetooth LE 500 Kbps

| Parameter | Description | Min | Typ | Max | Unit |
|-------------------------------------|---------------------------------|-----|------|-----|------|
| Sensitivity @30.8% PER | — | — | -100 | — | dBm |
| Maximum received signal @30.8% PER | — | — | 8 | — | dBm |
| Co-channel C/I | $F = F_0 \text{ MHz}$ | — | 4 | — | dB |
| Adjacent channel selectivity C/I | $F = F_0 + 1 \text{ MHz}$ | — | 1 | — | dB |
| | $F = F_0 - 1 \text{ MHz}$ | — | 0 | — | dB |
| | $F = F_0 + 2 \text{ MHz}$ | — | -24 | — | dB |
| | $F = F_0 - 2 \text{ MHz}$ | — | -24 | — | dB |
| | $F = F_0 + 3 \text{ MHz}$ | — | -37 | — | dB |
| | $F = F_0 - 3 \text{ MHz}$ | — | -39 | — | dB |
| | $F > F_0 + 3 \text{ MHz}$ | — | -38 | — | dB |
| | $F > F_0 - 3 \text{ MHz}$ | — | -42 | — | dB |
| Image frequency | — | — | -38 | — | dB |
| Adjacent channel to image frequency | $F = F_{image} + 1 \text{ MHz}$ | — | -42 | — | dB |
| | $F = F_{image} - 1 \text{ MHz}$ | — | -37 | — | dB |

5 Module Schematics

This is the reference design of the module.

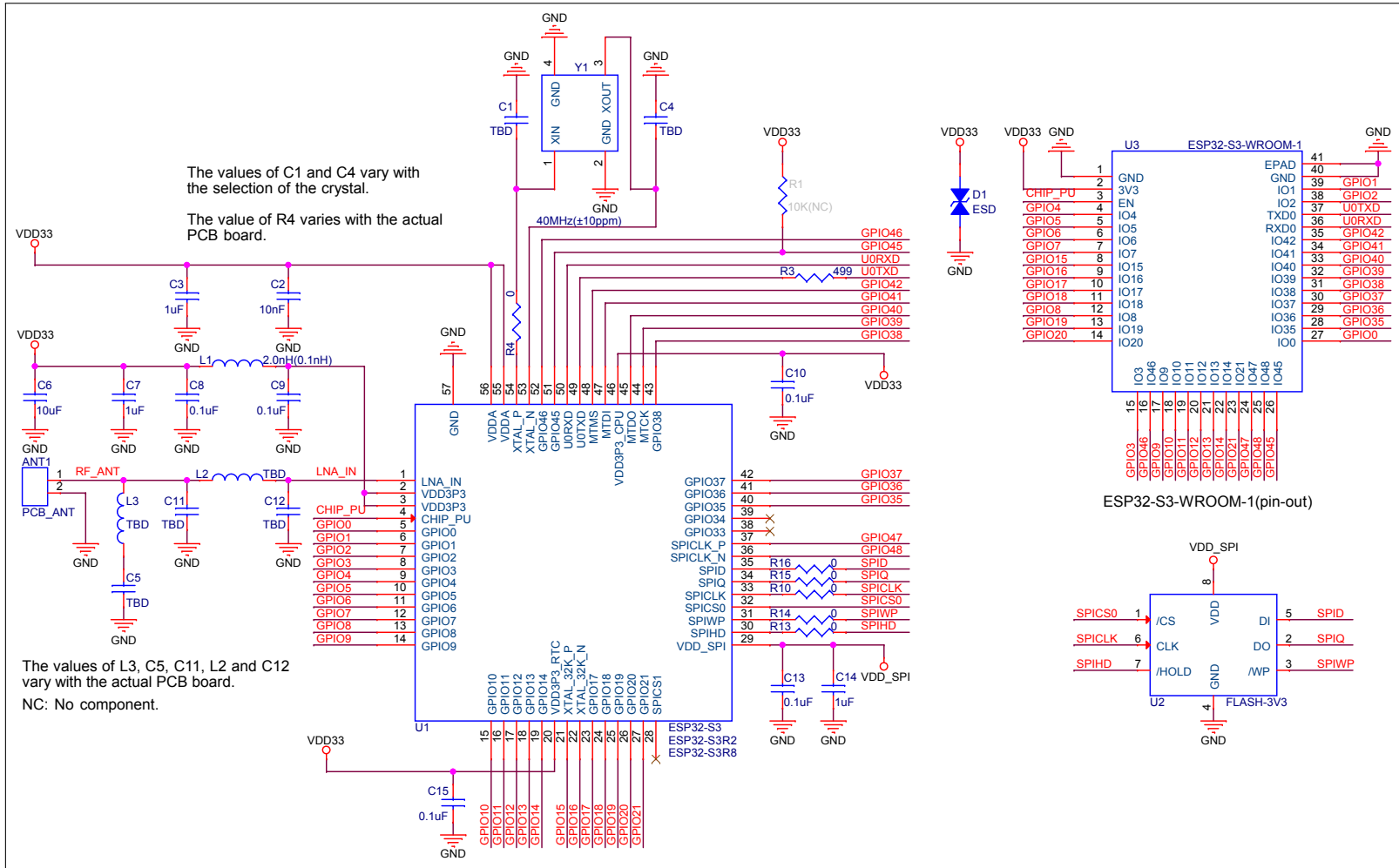


Figure 5: ESP32-S3-WROOM-1 Schematics

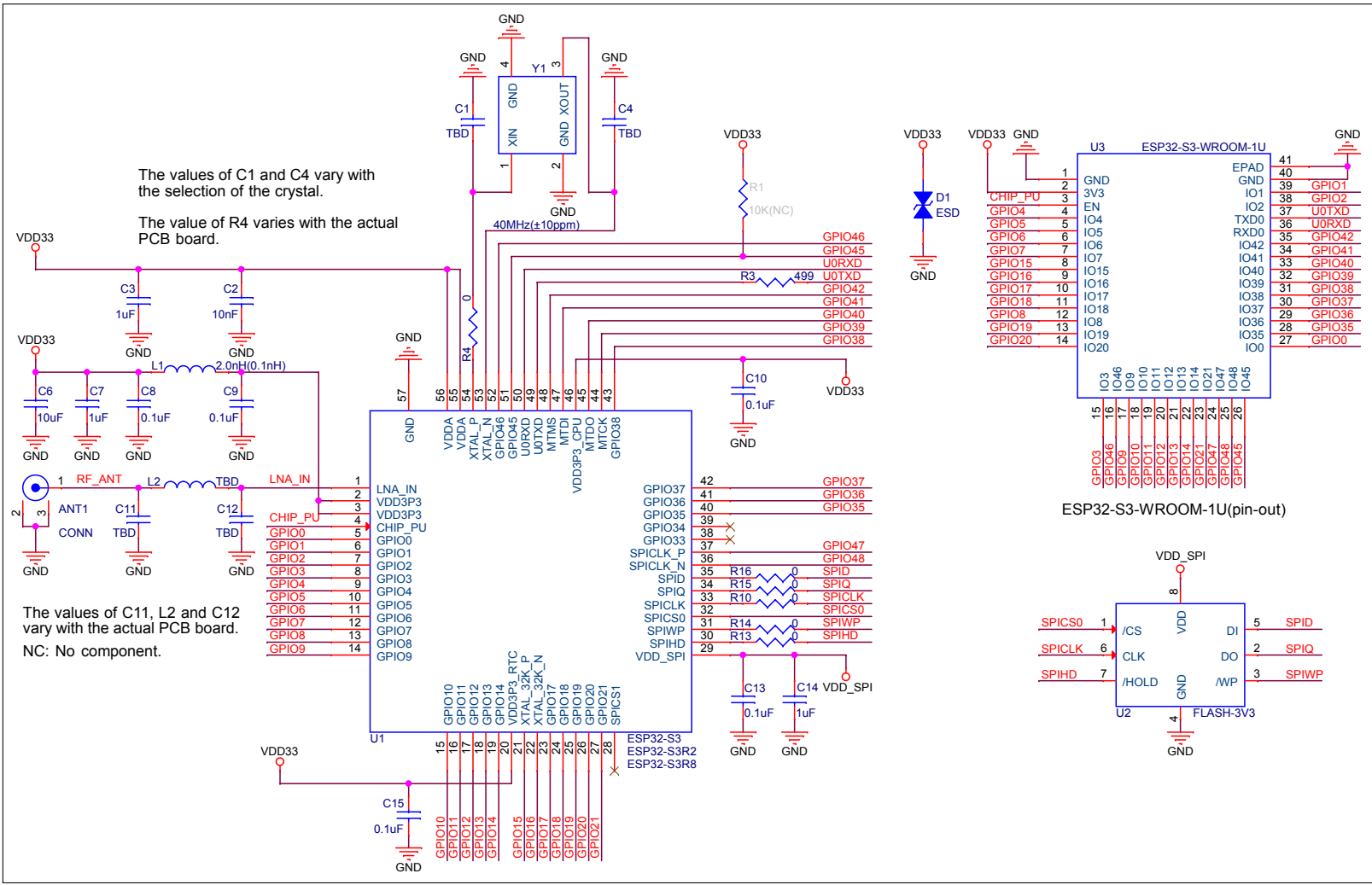


Figure 6: ESP32-S3-WROOM-1U Schematics

Internal pull-up resistor (R1) for IO45 is not populated in the module, as the flash in the module works at 3.3 V by default (output by VDD_SPI). Please make sure IO45 is not pulled high when the module is powered up by external circuit.

7 Physical Dimensions and PCB Land Pattern

7.1 Physical Dimensions

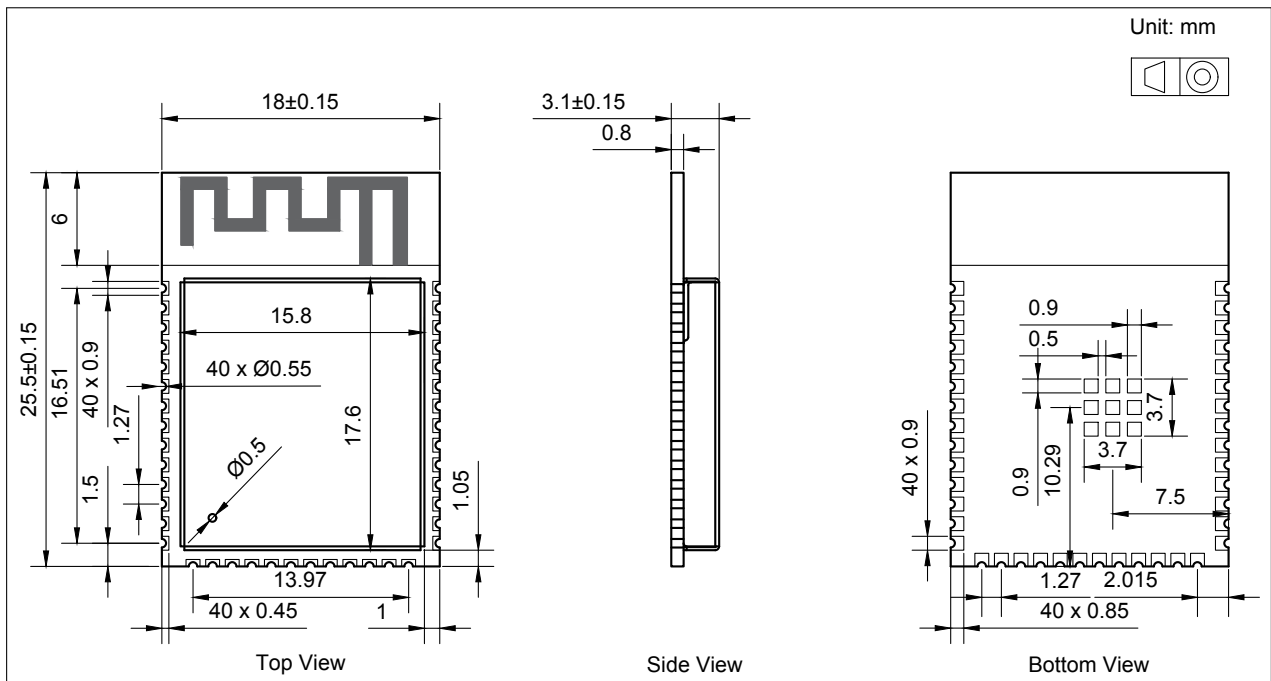


Figure 8: ESP32-S3-WROOM-1 Physical Dimensions

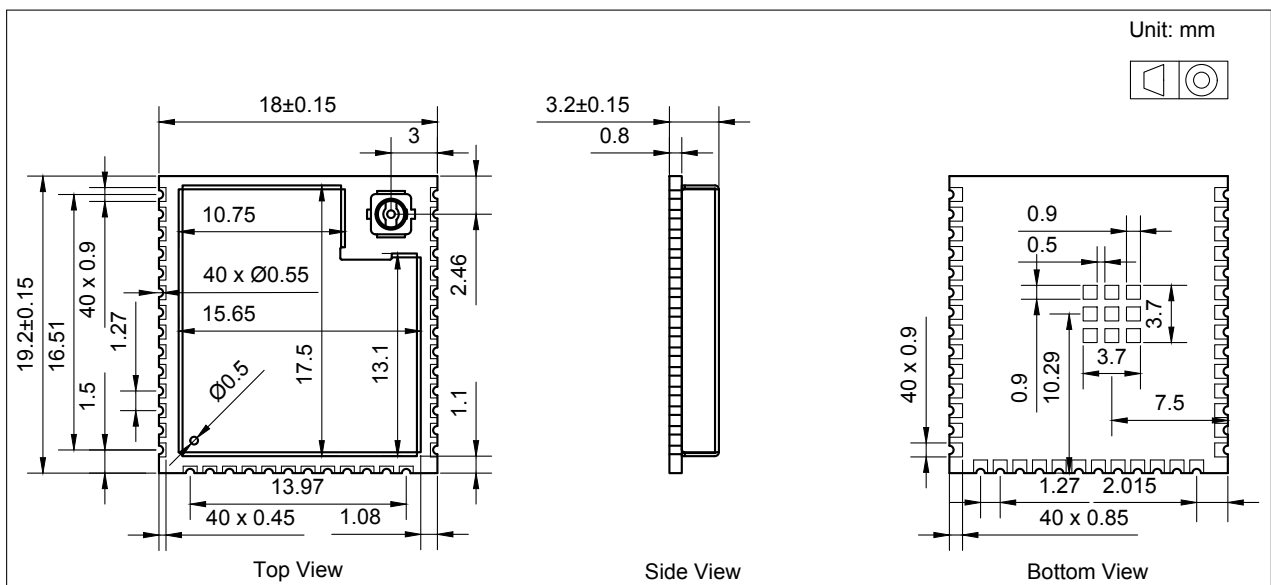


Figure 9: ESP32-S3-WROOM-1U Physical Dimensions

Note:

For information about tape, reel, and product marking, please refer to [Espressif Module Packaging Information](#).

7.2 Recommended PCB Land Pattern

This section provides the following resources for your reference:

- Figures for recommended PCB land patterns with all the dimensions needed for PCB design. See Figure 10 *ESP32-S3-WROOM-1 Recommended PCB Land Pattern* and Figure 11 *ESP32-S3-WROOM-1U Recommended PCB Land Pattern*.
- Source files of recommended PCB land patterns to measure dimensions not covered in Figure 10 and Figure 11. You can view the source files for [ESP32-S3-WROOM-1](#) and [ESP32-S3-WROOM-1U](#) with [Autodesk Viewer](#).
- 3D models of [ESP32-S3-WROOM-1](#). Please make sure that you download the 3D model file in .STEP format (beware that some browsers might add .txt).

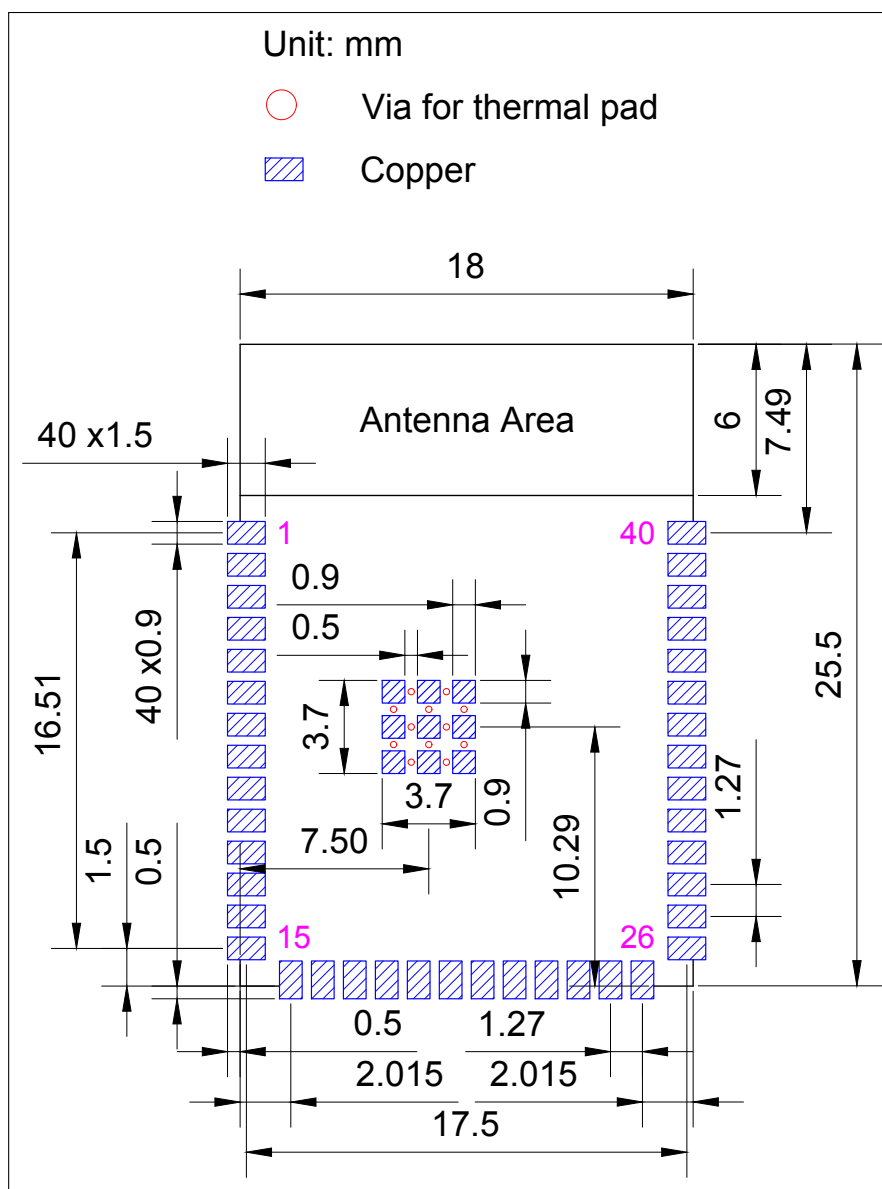


Figure 10: ESP32-S3-WROOM-1 Recommended PCB Land Pattern

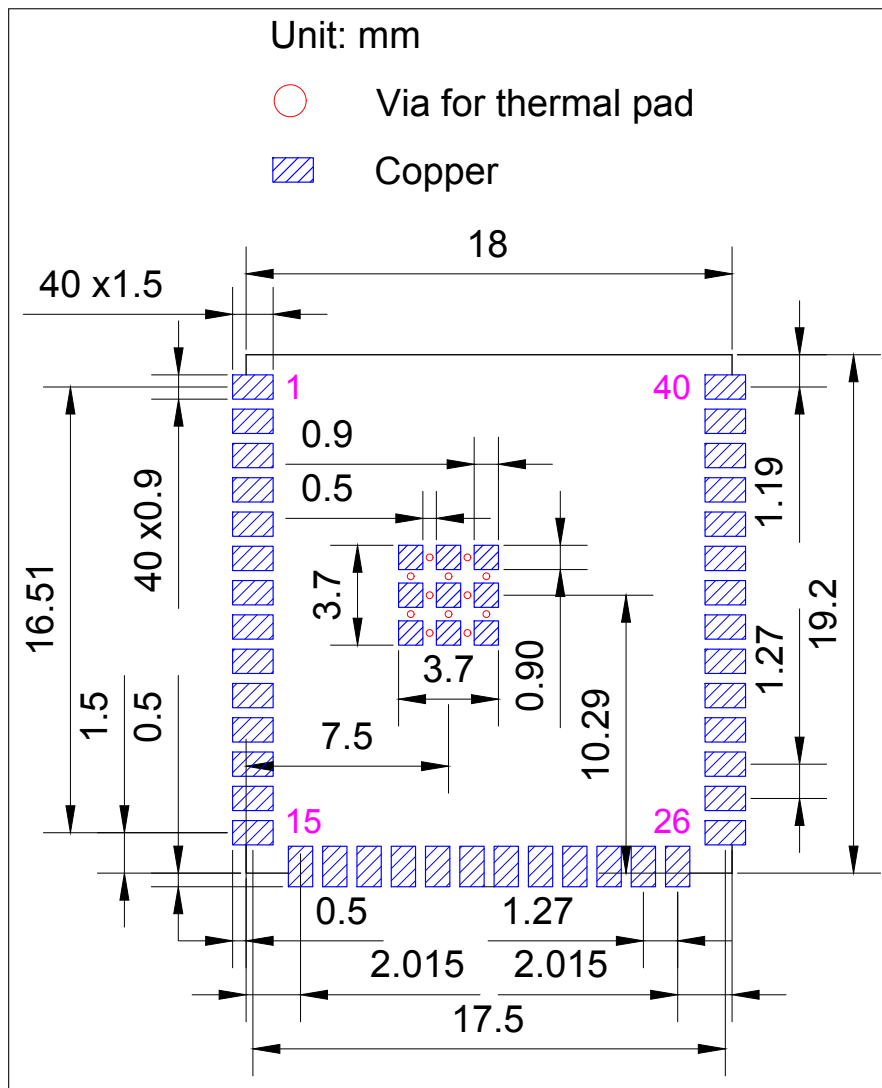


Figure 11: ESP32-S3-WROOM-1U Recommended PCB Land Pattern

7.3 Dimensions of External Antenna Connector

ESP32-S3-WROOM-1U uses the first generation external antenna connector as shown in Figure 12 *Dimensions of External Antenna Connector*. This connector is compatible with the following connectors:

- U.FL Series connector from Hirose
- MHF I connector from I-PEX
- AMC connector from Amphenol

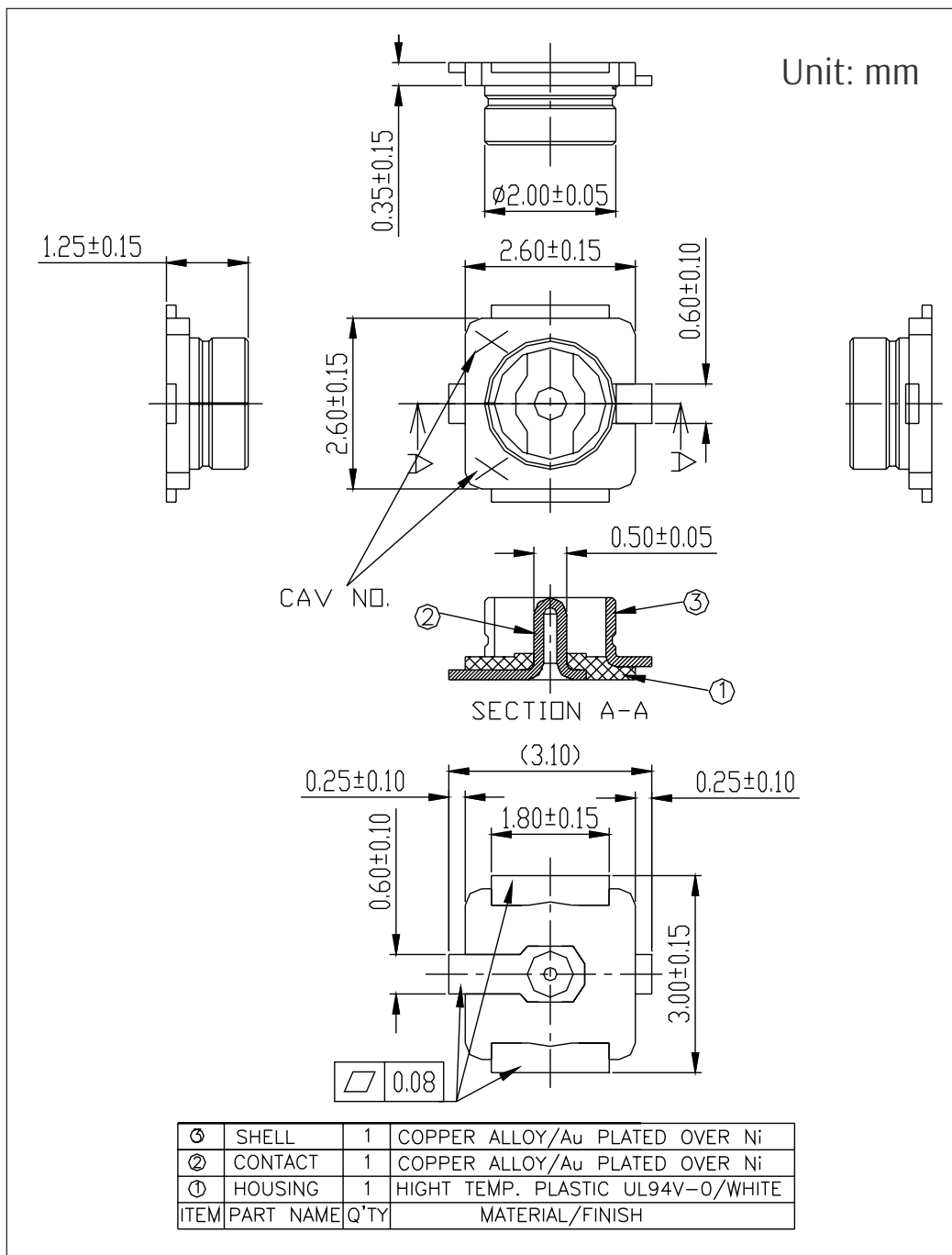


Figure 12: Dimensions of External Antenna Connector

8 Product Handling

8.1 Storage Conditions

The products sealed in moisture barrier bags (MBB) should be stored in a non-condensing atmospheric environment of $< 40\text{ }^{\circ}\text{C}$ and 90%RH. The module is rated at the moisture sensitivity level (MSL) of 3.

After unpacking, the module must be soldered within 168 hours with the factory conditions $25\pm 5\text{ }^{\circ}\text{C}$ and 60%RH. If the above conditions are not met, the module needs to be baked.

8.2 Electrostatic Discharge (ESD)

- Human body model (HBM): $\pm 2000\text{ V}$
- Charged-device model (CDM): $\pm 500\text{ V}$

8.3 Soldering Profile

8.3.1 Reflow Profile

Solder the module in a single reflow.

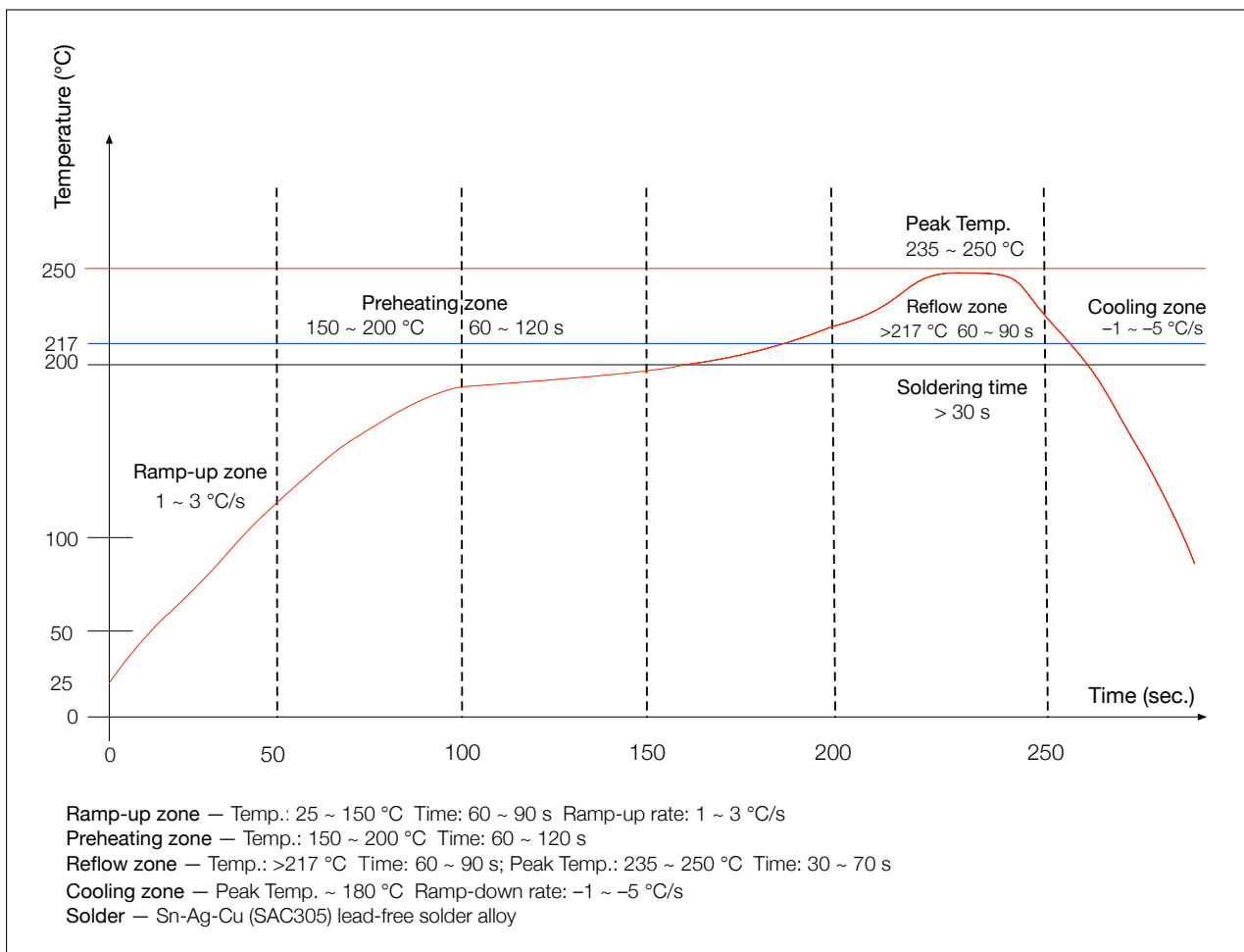


Figure 13: Reflow Profile

8.4 Ultrasonic Vibration

Avoid exposing Espressif modules to vibration from ultrasonic equipment, such as ultrasonic welders or ultrasonic cleaners. This vibration may induce resonance in the in-module crystal and lead to its malfunction or even failure. As a consequence, **the module may stop working or its performance may deteriorate.**

9 Related Documentation and Resources

Related Documentation

- [ESP32-S3 Series Datasheet](#) – Specifications of the ESP32-S3 hardware.
- [ESP32-S3 Technical Reference Manual](#) – Detailed information on how to use the ESP32-S3 memory and peripherals.
- [ESP32-S3 Hardware Design Guidelines](#) – Guidelines on how to integrate the ESP32-S3 into your hardware product.
- [ESP32-S3 Series SoC Errata](#) – Descriptions of known errors in ESP32-S3 series of SoCs.
- *Certificates*
<https://espressif.com/en/support/documents/certificates>
- *ESP32-S3 Product/Process Change Notifications (PCN)*
<https://espressif.com/en/support/documents/pcns?keys=ESP32-S3>
- *ESP32-S3 Advisories* – Information on security, bugs, compatibility, component reliability.
<https://espressif.com/en/support/documents/advisories?keys=ESP32-S3>
- *Documentation Updates and Update Notification Subscription*
<https://espressif.com/en/support/download/documents>

Developer Zone

- [ESP-IDF Programming Guide for ESP32-S3](#) – Extensive documentation for the ESP-IDF development framework.
- *ESP-IDF* and other development frameworks on GitHub.
<https://github.com/espressif>
- *ESP32 BBS Forum* – Engineer-to-Engineer (E2E) Community for Espressif products where you can post questions, share knowledge, explore ideas, and help solve problems with fellow engineers.
<https://esp32.com/>
- *The ESP Journal* – Best Practices, Articles, and Notes from Espressif folks.
<https://blog.espressif.com/>
- See the tabs *SDKs and Demos, Apps, Tools, AT Firmware*.
<https://espressif.com/en/support/download/sdks-demos>

Products

- *ESP32-S3 Series SoCs* – Browse through all ESP32-S3 SoCs.
<https://espressif.com/en/products/socs?id=ESP32-S3>
- *ESP32-S3 Series Modules* – Browse through all ESP32-S3-based modules.
<https://espressif.com/en/products/modules?id=ESP32-S3>
- *ESP32-S3 Series DevKits* – Browse through all ESP32-S3-based devkits.
<https://espressif.com/en/products/devkits?id=ESP32-S3>
- *ESP Product Selector* – Find an Espressif hardware product suitable for your needs by comparing or applying filters.
<https://products.espressif.com/#/product-selector?language=en>

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<https://espressif.com/en/contact-us/sales-questions>

Revision History

| Date | Version | Release notes |
|------------|---------|--|
| 2023-03-07 | v1.2 | <ul style="list-style-type: none"> • Update Section 3.3 Strapping Pins • Update Section 4.4 Current Consumption Characteristics • Update the minimum value of RF transmit power in Section 4.6.1 Bluetooth LE RF Transmitter (TX) Specifications • Update descriptions in Section 6 Peripheral Schematics • Add descriptions in Section 7.2 Recommended PCB Land Pattern • Update Section 9 Related Documentation and Resources • Other minor changes |
| 2022-07-22 | v1.1 | <ul style="list-style-type: none"> • Update Table 1 and Table 2 • Other minor updates |
| 2022-04-21 | v1.0 | <ul style="list-style-type: none"> • Update Bluetooth LE RF data • Update power consumption data in Table 14 • Add certification and test information • Update Section 3.3 |
| 2021-10-29 | v0.6 | Overall update for chip revision 1 |
| 2021-07-19 | v0.5.1 | Preliminary release, for chip revision 0 |



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